

FAST HIGH VOLTAGE TRANSISTOR SWITCHES

These MOSFET switches are designed for general high voltage switching applications such as pockels cell drivers, deflection and acceleration grid drivers, piezo drivers, MCP/SEV pulsers and DC/DC converters. The switching modules incorporate all features of the well known HTS switch family: Easy handling, high reliability, low jitter and precise switching. In contrast to conventional high voltage switches like spark gaps, electron tubes, gas discharge tubes and mechanical switches, HTS transistor switches show very stable switching characteristics independent of temperature and age. The mean time between failures (MTBF) is by several orders of magnitude higher than that of the classical HV switches. The switching modules are controlled by an interference-proof driver circuit which provides signal conditioning, auxiliary voltage monitoring, frequency limitation and temperature protection. In case of false operating conditions the switches are immediately turned-off and a fault signal is generated (not available for "pigtail" devices). The switches are turned-on by a positive going signal of 2 to 10 volts amplitude. The on-time may be varied between 100 ns and infinity. A short recovery time of 300 ns allows burst frequencies up to 3.3 MHz. Due to the galvanic isolation of more than 10 kV the switches may simply be operated also in high-side circuits. Three housing options are available to meet individual electrical and constructive requirements. The plastic case is the cost-effective standard package in low frequency, pulsed power applications with a low continuous power dissipation. The standard housing has soldering terminals and "pigtailed" for connection. It is also available as a printed circuit board version with soldering pins at bottom (option 06). To increase the Maximum Power Dissipation $P_{d(max)}$ the plastic modules can additionally be fitted with non-isolated cooling fins (option 04), which improve the $P_{d(max)}$ value by approximately the factor 5. A metal case for a continuous power dissipation of up to 400 Watt is also available (option 05, cf. data sheet "High Power Metal Case"). For detailed design recommendations please refer to the general instructions.

HTS 21-14

2000 VDC/ 140 Amps

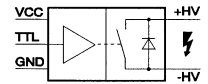
HTS 31-06

3000 VDC / 60 Amps

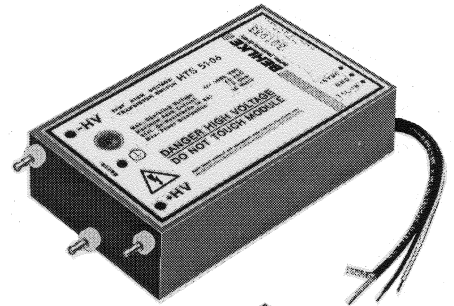
HTS 51-06

5000 VDC / 60 Amps

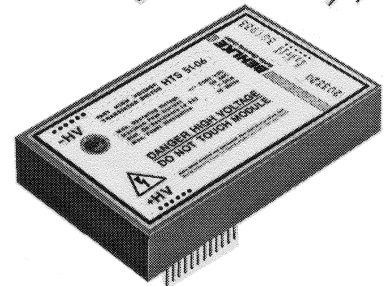
**Low Impedance
Variable On-Time**



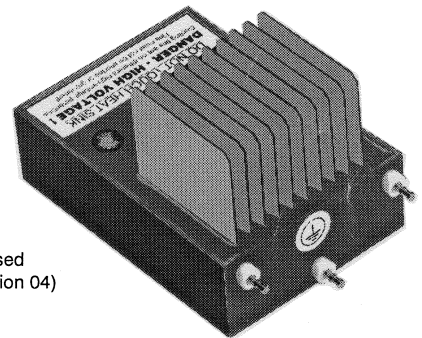
Standard plastic case with pigtail connection



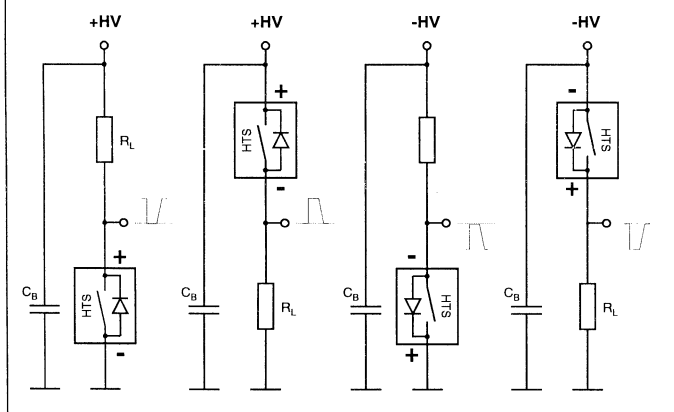
Plastic case for PCB insertion (flat version, option 06-B).



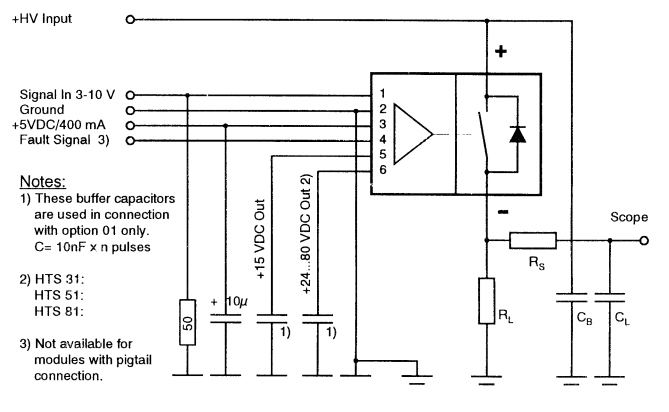
Standard plastic case with copper cooling fins for increased power dissipation (option 04)



Basic Circuits



Test Circuit



TECHNICAL DATA

Specification	Symbol	Condition / Comment	21-14	31-06	51-06	Unit		
Maximum Operating Voltage	$V_{O(max)}$	$I_{off} < 10 \mu ADC$	2000	3000	5000	VDC		
Minimum Operating Voltage	$V_{O(min)}$	Increased $t_{r(on)}$ and $t_{r(off)}$ below $0.1 \times V_{O(max)}$	0			VDC		
Typical Breakdown Voltage	V_{br}	$I_{off} > 1mADC$, $T_{case} = 70^\circ C$	2200	3300	5500	VDC		
Galvanic Isolation	V_I	HV part against control, standard	>10000			VDC		
Maximum Peak Current	$I_{P(max)}$	$T_{case} = 25^\circ C$	$t_p < 10 \mu s$, duty cycle <1%	140	60	60	ADC	
			$t_p < 100 \mu s$, duty cycle <1%	112	48	48		
			$t_p < 1 ms$, duty cycle <1%	79	34	34		
Maximum Continuous Load Current	I_L	$T_{case} = 25^\circ C$	Standard plastic case	2.2	1.2	0.9	ADC	
		respectively	Ditto + option 03	2.7	1.5	1.2		
		$T_{fin} = 25^\circ C$	Ditto +cooling fins (opt. 04)	5.5	3	2.3		
			Metal case B1 (opt. 05)	14.1	6.1	6		
Static On-Resistance	R_{stat}	$T_{case} = 25^\circ C$	$0.1 \times I_{P(max)}$	1	3	5	Ω	
			@ $I_{P(max)}$	2	6.5	11		
Maximum Off-State Current	I_{off}	$0.8 \times V_O$, $T_{case} = 25...70^\circ C$	5			μADC		
Turn-On Delay Time	$t_{d(on)}$	@ $I_{P(max)}$	100			ns		
Typical Turn-On Rise Time	$t_{r(on)}$	$0.8 \times V_O$, 10-90 %	$0.1 \times I_{P(max)}$	5	4.5	4.0	ns	
			$1.0 \times I_{P(max)}$	25	14	15		
Typical Turn-Off Rise Time	$t_{r(off)}$	$0.8 \times V_O$, $0.1 \times I_{P(max)}$, resistive load, 10-90%			8	ns		
Minimum On-Time	$t_{on(min)}$	Limited by driver circuit			100	ns		
Maximum On-Time	$t_{on(max)}$	Please note possible $P_{d(max)}$ limitations			∞			
Switch Recovery Time	t_{rc}	t_{rc} = minimum pulse spacing			300	ns		
Typical Turn-On Jitter	$t_{j(on)}$	$V_{aux} / V_{tr} = 5.0$ VDC			100	ps		
Max. Switching Frequency	$f_{(max)}$	Please note possible $P_{d(max)}$ limitations			50	70	50	kHz
Maximum Burst Frequency	$f_{b(max)}$	Use option 01 for >10 pulses within <20 μs			3.3		MHz	
Maximum Continuous Power Dissipation	$P_{d(max)}$	$T_{case} = 25^\circ C$	Standard plastic case	10	10	10	Watts	
		respectively	Ditto + option 03	15	15	15		
		$T_{fin} = 25^\circ C$	Ditto +cooling fins (opt. 04)	60	36	60		
			Metal case B1 (opt. 05)	400	240	400		
Linear Derating		Above $25^\circ C$	Standard plastic case	0.22	0.22	0.22	W/K	
			Ditto + option 03	0.33	0.33	0.33		
			Ditto + cooling fins (opt. 04)	1.33	0.8	1.33		
			Metal case B1 (opt. 05)	6.66	4	6.66		
Temperature Range	T_O	Plastic case, plastic case +cooling fins Metal case B1 (option 05)	-40...70 -30...85			$^\circ C$		
Natural Capacitance	C_N	Capacitance between switch poles at $V_{O(max)}$	60	75	45	pF		
Coupling Capacitance	C_C	HV side against control side	16	12	16	pF		
Diode Reverse Recovery Time	t_{rrc}	$I_F = 0.1 \times I_{P(max)}$	MOSFET parasitic diode		500	ns		
Diode Forward Voltage Drop	V_F	$I_F = 0.1 \times I_{P(max)}$	MOSFET parasitic diode		6	3.6	6	VDC
Auxiliary Supply Voltage	V_{aux}	Stabilized to $\pm 5\%$			5.0	VDC		
Auxiliary Supply Current	I_{aux}	@ f_{max}			400	mADC		
Control Signal	V_{tr}	> 3VDC recommended			2-10	VDC		
Fault Signal Output		TTL compatible, short circuit proof, L=Fault			H= 4 V, L= 0.5 V	VDC		
Dimensions	LxBxH	Standard plastic case			89 x 64 x 27		mm ³	
		Flat plastic case (opt. 06-B)			89 x 64 x 19			
		Plastic case + cooling fins (opt. 04)			89 x 64 x 60			
		Metal case B1 (opt. 05)			180 x 100 x 53.5			
Weight		Standard plastic case			250		g	
		Flat plastic case (opt. 06-B)			190			
		Plastic case + cooling fins (opt. 04)			350			
		Metal case B1 (opt. 05)			2500			

Ordering Informations

HTS 21-14 Transistor switch, 2000 VDC, 140 Amps.
HTS 31-06 Transistor switch, 3000 VDC, 60 Amps.
HTS 51-06 Transistor switch, 5000 VDC, 60 Amps.
Option 01 High frequency burst
Option 02 Flame retardend casting resin UL94-VO
Option 03 Increased thermal conductivity

Option 04 Cooling fins, non-isolated
Option 05 Metal case B1, potential-free (cf. separate data sheet)
Option 06 Soldering pins for printed boards, module height 27 mm
Option 06-B Ditto, module height 19 mm (options 02, 03, 04 excluded)
Option 08 30 kV instead of 10 kV isolation, module size on request
Option 08-B 80 kV instead of 10 kV isolation, module size on request

All data and specifications subject to change without notice. Custom designed devices on request.